
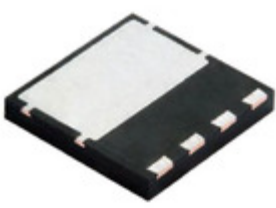



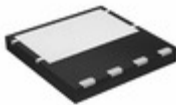
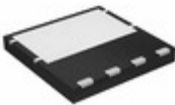
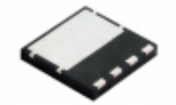

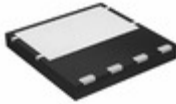
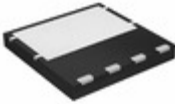

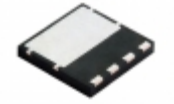
|  |   |
|--|---|
|   | <h2 style="color: red;">SIHH24N65EF-T1-GE3</h2>   |
| <br> | <b>Hersteller-Teilenummer:</b> <a href="#">SIHH24N65EF-T1-GE3</a>   |
|  | <b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a>   |
|  | <b>Teil der Beschreibung:</b> MOSFET N-CHAN 650V 23A POWERPAK   |
|  | <b>Datenblätter:</b>  <a href="#">SIHH24N65EF-T1-GE3.pdf</a> |
|  | <b>RoHs Status:</b> Bleifrei / RoHS-konform   |
|  | <b>Lagerzustand:</b> New original, Stock Available.   |
| <b>Liefern von:</b> Hong Kong  |   |
| <b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS   |   |
| <p>Image may be representation.<br/>See specs for product details.</p>   |   |

### Spezifikationen

|  |   |
|--|---|
| Teilenummer                                      | <a href="#">SIHH24N65EF-T1-GE3</a>  |
| Hersteller                                       | <a href="#">Vishay / Siliconix</a>  |
| Beschreibung                                     | MOSFET N-CHAN 650V 23A POWERPAK   |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> , |
| Teilstatus                                       | <a href="#">Require For Quote &amp; Check Stock</a>                               |
| VGS (th) (Max) @ Id                              | 4V @ 250µA  |
| Vgs (Max)  | ±30V  |
| Technologie                                      | MOSFET (Metal Oxide)  |
| Supplier Device-Gehäuse                          | PowerPAK® 8 x 8   |
| Serie  | -   |
| Rds On (Max) @ Id, Vgs                           | 158 mOhm @ 12A, 10V   |
| Verlustleistung (max)                            | 202W (Tc)   |
| Verpackung                                       | Original-Reel®  |
| Verpackung / Gehäuse                             | 8-PowerTDFN   |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                  | Surface Mount   |
| Eingabekapazität (Ciss) (Max) @ Vds              | 2780pF @ 100V   |
| Gate Charge (Qg) (Max) @ Vgs                     | 17nC @ 10V  |
| Typ FET  | N-Channel   |
| FET-Merkmal                                      | -   |
| Antriebsspannung (Max Rds On, Min Rds On)        | 10V   |
| Drain-Source-Spannung (Vdss)                     | 650V  |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 23A (Tc)  |

SIHH24N65EF-T1-GE3 Electronic Components ist ein 100% neues Original von YIC Distributor, SIHH24N65EF-T1-GE3-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, SIHH24N65EF-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.  
RFQ SIHH24N65EF-T1-GE3 E-Mail: [Info@Y-IC.com](mailto:Info@Y-IC.com)

### Sie können auch interessiert

|  |   |  |   |
|--|---|--|---|
| <p>sein:</p>  <p><b>SIHH21N65EF-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CH 650V 19.8A<br/>POWERPAK</p> |  <p><b>SIHH21N65EF-T1-GE3</b><br/>Vishay Siliconix<br/>MOSFET N-CH 650V 19.8A<br/>POWERPAK</p>             |  <p><b>SIHH24N65E-T1-GE3</b><br/>Vishay Siliconix<br/>MOSFET N-CHAN 650V 23A<br/>POWERPAK</p>              |  <p><b>SIHH26N60EF-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CHAN 600V 24A<br/>POWERPAK</p> |
|  <p><b>SIHH27N60EF-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CH 600V 29A<br/>POWERPAK8</p>               |  <p><b>SIHH26N60E-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CH 600V 25A<br/>POWERPAK8X8</p> |  <p><b>SIHH24N65EF-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CHAN 650V 23A<br/>POWERPAK</p> |  <p><b>SIHH26N60EF-T1-GE3</b><br/>Vishay Siliconix<br/>MOSFET N-CHAN 600V 24A<br/>POWERPAK</p>             |

### Verwandtes Hot-Keyword

Mehr

|   |  |   |  |   |
|---|--|---|--|---|
| <a href="#">SIHH24N65EF-T1-GE3 Vishay / Siliconix</a> | <a href="#">SIHH24N65EF-T1-GE3 Datenblatt</a>  | <a href="#">SIHH24N65EF-T1-GE3-Datenblätter</a> | <a href="#">SIHH24N65EF-T1-GE3 PDF</a>   | <a href="#">Vishay / Siliconix SIHH24N65EF-T1-GE3</a> |
| <a href="#">SIHH24N65EF-T1-GE3 Electronic</a>         | <a href="#">SIHH24N65EF-T1-GE3-Komponenten</a> | <a href="#">SIHH24N65EF-T1-GE3-Verteiler</a>    | <a href="#">SIHH24N65EF-T1-GE3-Bild</a>  | <a href="#">SIHH24N65EF-T1-GE3-Teil</a>               |
| <a href="#">SIHH24N65EF-T1-GE3 Preis</a>              | <a href="#">SIHH24N65EF-T1-GE3 Hersteller</a>  | <a href="#">SIHH24N65EF-T1-GE3 Bild</a>         | <a href="#">SIHH24N65EF-T1-GE3 Aktie</a> | <a href="#">SIHH24N65EF-T1-GE3 Inventar</a>           |
| <a href="#">SIHH24N65EF-T1-GE3 Neu</a>                | <a href="#">SIHH24N65EF-T1-GE3 Original</a>    | <a href="#">SIHH24N65EF-T1-GE3 garantiert</a>   | <a href="#">SIHH24N65EF-T1-GE3 RFQ</a>   | <a href="#">SIHH24N65EF-T1-GE3 Online bestellen</a>   |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited